LM49150

LM49150 Mono Class D Audio Subsystem with Earpiece Driver and StereoGround Referenced Headphone Amplifiers



Literature Number: SNAS439B



LM49150

Boomer® Audio Power Amplifier Series

Mono Class D Audio Subsystem with Earpiece Driver and Stereo Ground Referenced Headphone Amplifiers

General Description

The LM49150 is a fully integrated audio subsystem designed for portable handheld applications such as cellular phones. Part of National's Power Wise® product family, the LM49150 consumes very low power in the various modes of operation and still providing great audio performance. The LM49150 combines a 1.25W mono E²S (Enhanced Emission Suppression) class D amplifier, 135mW Class AB earpiece amplifier, 42mW/channel stereo ground reference headphone amplifiers, volume control, and mixing circuitry into a single device.

The filterless class D amplifier delivers 1.25W into an 8Ω load with <1% THD+N with a 5V supply. The E²S class D amplifier features a patented, ultra low EMI PWM architecture that significantly reduces RF emissions while preserving audio quality. The 42mW/channel headphone drivers feature National's ground referenced architecture that creates a ground-referenced output from a single supply, eliminating the need for bulky and expensive DC-blocking capacitors, saving space and minimizing cost.

The LM49150 features a fully differential mono input, and two single-ended stereo inputs. The three inputs can be mixed/multiplexed to either the speaker or headphone amplifiers. Each input channel has an independent, 32-step digital volume control. The headphone output stage features an additional, 8-step gain control, while the speaker output stage has a selectable 6dB or 12dB gain. The mixer, volume control and device mode select are controlled through an I²C compatible serial interface.

The LM49150's superior click and pop suppression eliminates audible transients on power-up/down and during shutdown. The LM49150 is available in a ultra-small 20-bump micro SMD package (2.225mm X 2.644mm).

Key Specifications

	Output	power a	at V _{DD}	= 5V:
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Speaker:	
$R_L = 8\Omega$ BTL, THD+N $\leq 1\%$	1.25W (typ)
Headphone:	
$R_1 = 32\Omega$ SE, THD+N $\leq 1\%$	42mW (typ)

March 4, 2009

Earpiece:

 $R_L = 8\Omega SE, THD+N \le 1\%$ 135mW (typ)

■ Output power at V_{DD} = 3.3V:

Speaker:

 $R_L = 8\Omega BTL, THD+N \le 1\%$ 520mW (typ)

Headphone:

 $R_L = 32\Omega BTL, THD+N \le 1\%$ 42mW (typ)

Earpiece:

 $R_L = 8\Omega \text{ SE, THD+N} \le 1\%$ 35mW (typ)

Output Offset

LS Mode 9mV (typ)
HP Mode 1mV (typ)
Earpiece 1mV (typ)

■ Single Supply Operation (V_{DD}) 2.7 to 5.5V

■ I²C Single Supply Operation 1.7 to 5.5V

Features

- E²S class D amplifier
- Ground referenced headphone outputs eliminates output coupling capacitors
- I²C volume and mode control
- Mono earpiece amplifier
- Flexible output for speaker and headphone output
- 20-bump micro SMD package
- Soft enable function
- "Click and Pop" suppression circuitry
- Thermal shutdown protection
- Low supply current
- Micro-power shutdown

Applications

- Mobile Phones
- PDAs
- Portable Electronics

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Typical Application

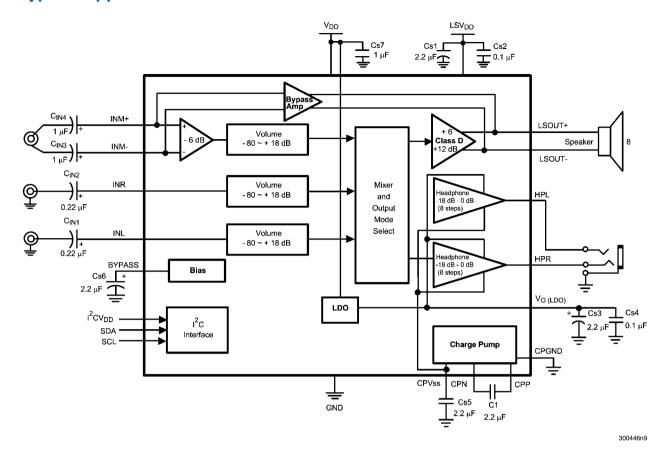
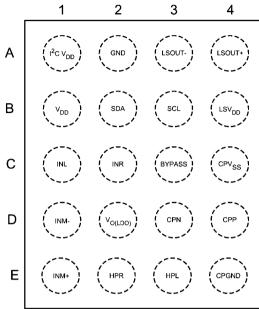


FIGURE 1. Typical Audio Amplifier Application Circuit-Output Capacitor-less

Connection Diagrams

20 Bump micro SMD Package



300446n8

Top View (Bump Side Down) (See NS Package Number TLA20KGA)

Top Markings



300446n7

Top View
XY - Date Code
TT - Die Traceability
G- Boomer
K7 - LM49150TL

Ordering Information

Ord	der Number	Package	Package DWG #	Transport Media	Green Status	
LI	.M49150TL	20 Bump micro SMD	TLA20KGA	250 units on tape and reel	NOPB	
LN	M49150TLX	20 Bump micro SMD	TLA20KGA	3000 units on tape and reel	NOPB	

Bump Descriptions

Bump	Name	Description
A1	I ² CV _{DD}	I ² C Power Supply
A2	GND	Ground
A3	LSOUT-	Inverting Loudspeaker Output
A4	LSOUT+	Non-Inverting Loudspeaker Output
B1	V _{DD}	Analog Power Supply
B2	SDA	I ² C Data Input
B3	SCL	I2C Clock Input
B4	LSV _{DD}	Loudspeaker Power Supply
C1	INL	Left Channel Input
C2	INR	Right Channel Input
C3	BYPASS	Mid-Rail Supply Bypass
C4	CPV _{SS}	Charge Pump Output
D1	INM-	Mono Channel Inverting Input
D2	V _{O(LDO)}	Internal LDO Output
D3	CPN	Charge Pump Flying Capacitor - Negative Terminal
D4	CPP	Charge Pump Flying Capacitor - Positive Terminal
E1	INM+	Mono Channel Non-Inverting Input
E2	HPR	Right Channel Headphone Amplifier Output
E3	HPL	Left Channel Headphone Amplifier Output
E4	CPGND	Charge Pump Ground

Package"

Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (Note 1) 6.0V
Storage Temperature -65°C to +150°C
Input Voltage -0.3 to V_{DD} +0.3
Power Dissipation (Note 3) Internally Limited
ESD Rating (Note 4) 2.0kV
ESD Rating (Note 5) 200V
Junction Temperature 150°C

Soldering Information
See AN-1112
"Micro SMD Wafer
Level Chip Scale

Thermal Resistance

 θ_{JA} (typ) - TLA20KGA 46.1°C/W

Operating Ratings

Temperature Range -40° C to 85°C Supply Voltage $2.7\text{V} \le \text{V}_{DD} \le 5.5\text{V}$ Supply Voltage (I²C) (Note 10) $1.7\text{V} \le \text{I2CV}_{DD} \le 5.5\text{V}$

Electrical Characteristics 3.3V (Note 2)

The following specifications apply for V_{DD} = LSV $_{DD}$ = 3.3V, A_V = 0dB, Loudspeaker R_L = 15 μ H+8 Ω +15 μ H (Note 8), Earpiece R_L = 8 Ω , f = 1kHz, unless otherwise specified. Limits apply for T_A = 25C. LS = Loudspeaker, HP = Headphone, EP = Earpiece.

			LM4	Units		
Symbol	Parameter	Conditions	Typical (Note 6)	Limits (Note 7)	(Limits)	
		V _{IN} = 0, No Load				
		LS mode 1	3.7	5	mA (max)	
		HP mode 8	4.7	6.7	mA (max)	
I_{DD}	Supply Current	EP Bypass mode	0.8	1.2	mA (max)	
		LS + HP mode 5 and mode 10	7	9.5	mA (max)	
		LS mode 1, GAMP_SD = 1	3	4	mA (max)	
		HP mode 8, GAMP_SD = 1	4.3	6.1	mA (max)	
I _{SD}	Shutdown Current		0.04	1	μA (max)	
V _{os}		V_{IN} = 0V, LS, R _L = 8 Ω LS Gain = 6dB, Stereo mode 10	9	40	mV (max)	
	Output Offset Voltage	V_{IN} = 0V, HP, R _L = 32 Ω Ground Referenced, Stereo mode 10	1	5	mV (max)	
		$V_{IN} = 0V$, EP Bypass only, $R_L = 8\Omega$	0.8	5	mV (max)	
		LS mode 1, THD+N = 1%, f = 1kHz	0.45		10/	
		LS Gain = 6dB, $R_L = 4\Omega$	845		mW	
		LS mode 1, THD+N = 1%, f = 1kHz	520	450	mW (min)	
		LS Gain = 6dB, $R_L = 8\Omega$	320	450	IIIVV (IIIIII)	
Po	Output Power	HP mode 8, THD+N = 1%, f = 1kHz HP Attenuation = 0dB, R_1 = 16Ω	42		mW	
		HP mode 8, THD+N = 1%, f = 1kHz HP Attenuation = 0dB, R_L = 32Ω	43	39	mW (min)	
		EP Bypass only, THD+N = 1%, f = 1kHz $R_L = 8\Omega$	35	28	mW (min)	
		LS mode 1, f = 1kHz $P_{OUT} = 250$ mW; $R_L = 8\Omega$	0.02		%	
THD+N	Total Harmonic Distortion + Noise	HP mode 8, f = 1kHz P_{OUT} = 20mW; R_L = 32 Ω	0.009		%	
		EP Bypass only, $f = 1kHz$ $P_{OUT} = 20mW$; $R_L = 8\Omega$	0.15		%	
 η	Efficiency	LS output	88		%	

			LM49150		Units			
Symbol	Parameter	Conditions	Typical (Note 6)	Limits (Note 7)	(Limits)			
		A-weighted,		,				
		inputs terminated to AC GND, Output referred						
		EP Bypass	11		μV			
		LS; Mode 1	41		μV			
Eou⊤	Output Noise	LS; Mode 2	41		μV			
		LS; Mode 3	43		μV			
		HP; Mode 4	9		μV			
		HP; Mode 8	10		μV			
		HP; Mode 12	12		μV			
		$V_{RIPPLE} = 200 \text{mV}_{PP}$; f = 217Hz, R _L = 8 Ω , C _B All audio inputs terminated to AC GND, out						
		EP Bypass	95		dB			
		Loudspeaker Output; LS Gain = 6dB						
		LS; Mode 1	72		dB			
PSRR	Power Supply Rejection Ratio	LS; Mode 2	67		dB			
		LS; Mode 3	71		dB			
		Headphone Output, HP Attenuation = 0dB						
		HP; Mode 4	91		dB			
		HP; Mode 8	83		dB			
		HP; Mode 12	81		dB			
	Volume Control Step Size Error		±0.2		dB			
		Maximum Attenuation	-92		dB			
	Digital Volume Control Range	Volume Step 2	-46.5	-49 -44	dB (mir dB (max			
		Maximum Gain	18	17 19	dB (mir dB (max			
A _M	Mute Attenuation	HP	98		dB			
- W	mate / titeriodileri	LS	98		dB			
	Mono Channel Input Impedance	Maximum gain setting	12.9	10 15	kΩ (min kΩ (max			
Z _{IN}	L _{IN} and R _{IN} Input Impedance	Maximum attenuation setting	111	90 130	kΩ (min kΩ (max			
	EP Bypass Resistance		62	50 80	kΩ (min kΩ (max			
		$f = 217Hz$, $V_{CM} = 1V_{P-P}$, $R_L = 8\Omega$ EP Bypass	55		dB			
CMRR	Common-Mode Rejection Ratio	$f = 217Hz$, $V_{CM} = 1V_{P-P}$, $R_L = 8\Omega$ LS, Mode 1	55		dB			
		$f = 217Hz$, $V_{CM} = 1V_{P-P}$, $R_L = 32\Omega$ HP, Mode 4	61		dB			
X _{TALK}	Crosstalk	HP mode 8; $P_0 = 12$ mW $R_L = 32\Omega$, $f = 1$ kHz	78		dB			
T	Turn-On Time	C _B = 2.2μF, HP, Normal Turn-On Mode	27		ms			
T _{ON}	Tuni-On Time	C _B = 2.2μF, HP, Fast Turn-On Mode	15		ms			

Electrical Characteristics 5.0V (Notes 2, 7)

The following specifications apply for V_{DD} = LSV $_{DD}$ = 5.0V, A_{V} = 0dB, Loudspeaker R_{L} = 15 μ H+8 Ω +15 μ H (Note 8), Earpiece R_{L} = 8 Ω , f = 1kHz, unless otherwise specified. Limits apply for T_{A} = 25C. LS = Loudspeaker, HP = Headphone, EP = Earpiece.

			LM4	LM49150		
Symbol	Parameter	Conditions	Typical (Note 6)	Limits (Note 7)	Units (Limits)	
		V _{IN} = 0, No Load		· · · · · · · ·		
		LS mode 1	4.5		mA	
		HP mode 8	4.9		mA	
DD	Supply Current	EP Bypass Mode	0.9		mA	
		LS + HP Mode 5 and Mode 10	7.7		mA	
		LS Mode 1, GAMP_SD = 1	3.7		mA	
		HP Mode 8, GAMP_SD = 1	4.4		mA	
SD	Shutdown Current		0.02	1	μA (max)	
		$V_{IN} = 0V$, LS, $R_L = 8\Omega$ LS Gain = 6dB, Stereo Mode 10	9	40	mV (max)	
V _{OS}	Output Offset Voltage	V_{IN} = 0V, HP, R _L = 32 Ω Ground Reference, Stereo Mode 10	1	5	mV (max)	
		$V_{IN} = 0V$, EP Bypass only, $R_I = 8\Omega$	1	5	mV (max)	
P _o		LS Mode 1, THD+N = 1%, f = 1kHz LS Gain = 6dB, R_L = 4 Ω	2.1		W	
	Output Power	LS Mode 1, THD+N = 1%, f = 1kHz LS Gain = 6dB, R_L = 8 Ω	1.25		W	
		HP Mode 8, THD+N = 1%, f = 1kHz HP Attenuation = 0dB, R_L = 16 Ω	42		mW	
		HP Mode 8, THD+N = 1%, f = 1kHz HP Attenuation = 0dB, R_L = 32 Ω	42		mW	
		EP Bypass Only, THD+N = 1% $f = 1kHz$, $R_L = 8\Omega$	135		mW	
		LS Mode 1, $f = 1kHz$ $P_{OUT} = 600mW$; $R_L = 8\Omega$	0.015		%	
THD+N	Total Harmonic Distortion + Noise	HP Mode 8, f = 1kHz $P_{OUT} = 20mW; R_L = 32\Omega$	0.01		%	
		EP Bypass only, $f = 1kHz$, $P_{OUT} = 60mW$; $R_L = 8\Omega$	0.08		%	
 า	Efficiency	LS Output	88		%	
		A-weighted, inputs terminated to AC GND, Output referred				
		EP Bypass	10		μV	
		LS; Mode 1	40		μV	
OUT	Output Noise	LS; Mode 2	47		μV	
_0.		LS; Mode 3	48		μV	
		HP; Mode 4	9		μV	
		HP; Mode 8	10		 μV	
		HP; Mode 12	11		 μV	

Symbol			LM4	9150	Unite
	Parameter	Conditions	Typical (Note 6)	Limits (Note 7)	Units (Limits)
		$V_{RIPPLE} = 200 \text{mV}_{PP}$; f = 217Hz, R _L = 8 Ω , C _B All audio inputs terminated to AC GND; outp			
		EP Bypass	97		dB
		Loudspeaker Output; LS Gain = 6dB	•	'	
		LS; Mode 1	75		dB
PSRR	Power Supply Rejection Ratio	LS; Mode 2	71		dB
		LS; Mode 3	71		dB
		Headphone Output, HP Attenuation = 0dB	,		
		HP; Mode 4	91		dB
		HP; Mode 8	80		dB
		HP; Mode 12	79		dB
	Volume Control Step Size Error		±0.2		dB
		Maximum Attenuation	-92		dB
	Digital Volume Control Range	Volume Step 2	-46.5	-49 -44	dB (min dB (max
		Maximum Gain	18	17 19	dB (min
		HP	98		dB
A _M	Mute Attenuation	LS	98		dB
	Mono Channel Input Impedance	Maximum gain setting	12		kΩ
_	L _{IN} and R _{IN} Input Impedance	Maximum attenuation setting	111		kΩ
Z _{IN}	EP Bypass Resistance		62	50 80	kΩ (min)
		$f = 217Hz$, $V_{CM} = 1V_{P-P}$, $R_L = 8\Omega$ EP Bypass	55		dB
CMRR	Common-Mode Rejection Ratio	$f = 217Hz$, $V_{CM} = 1V_{P-P}$, $R_L = 8\Omega$ LS, Mode 1	55		dB
		$f = 217Hz$, $V_{CM} = 1V_{P-P}$, $R_L = 32\Omega$ HP, Mode 4	61		dB
X _{TALK}	Crosstalk	HP mode 8; $P_O = 12mW$ $R_L = 32\Omega$, $f = 1kHz$	78		dB
т	Turn On Time	$C_B = 2.2\mu F$, HP, Normal Turn-On Mode	27		ms
T _{ON}	Turn-On Time	C _B = 2.2μF, HP, Fast Turn-On Mode	15		ms

I2C micro (Note 2)

The following specifications apply for $V_{DD} = 5.0V$ and 3.3V, $T_A = 25^{\circ}C$, $2.2V \le I^2C_{DD} \le 5.5V$, unless otherwise specified.

			L	Units		
Symbol	Parameter	Conditions	Typical (Note 4)	Limits (Notes 7, 5)	(Limits)	
t ₁	I ² C Clock Period			2.5	μs (min)	
t ₂	I ² C Data Setup Time			100	ns (min)	
t ₃	I ² C Data Stable Time			0	ns (min)	
t ₄	Start Condition Time			100	ns (min)	
t ₅	Stop Condition Time			100	ns (min)	
t ₆	I ² C Data Hold Time			100	ns (min)	
V _{IH}	I ² C Input Voltage High			0.7xl ² CV _{DD}	V (min)	
V _{IL}	I ² C Input Voltage Low			0.3xl ² CV _{DD}	V (max)	

I2C micro (Note 2)

The following specifications apply for V_{DD} = 5.0V and 3.3V, T_A = 25°C, 1.7V \leq I²C_V_{DD} \leq 2.2V, unless otherwise specified.

			L	M49150	Units	
Symbol	Parameter	Conditions	Typical (Note 6)	Limits (Note 7)	(Limits)	
t ₁	I ² C Clock Period			2.5	μs (min)	
t ₂	I ² C Data Setup Time			250	ns (min)	
t ₃	I ² C Data Stable Time			0	ns (min)	
t ₄	Start Condition Time			250	ns (min)	
t ₅	Stop Condition Time			250	ns (min)	
t ₆	I ² C Data Hold Time			250	ns (min)	
V _{IH}	I ² C Input Voltage High			0.7xl ² CV _{DD}	V (min)	
V _{IL}	I ² C Input Voltage Low			0.3xl2CV _{DD}	V (max)	

Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified

Note 2: The Electrical Characteristics tables list guaranteed specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not guaranteed.

Note 3: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX} , θ_{JA} , and the ambient temperature, T_A . The maximum allowable power dissipation is $P_{DMAX} = (T_{JMAX} - T_A) / \theta_{JA}$ or the number given in *Absolute Maximum Ratings*, whichever

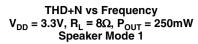
Note 4: Human body model, applicable std. JESD22-A114C.

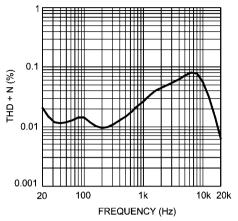
Note 5: Machine model, applicable std. JESD22-A115-A.

Note 6: Typical values represent most likely parametric norms at T_A = +25°C, and at the *Recommended Operation Conditions* at the time of product characterization and are not guaranteed.

Note 7: Datasheet min/max specification limits are guaranteed by test or statistical analysis.

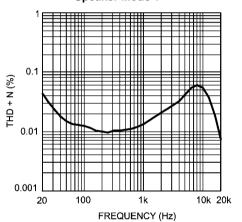
Typical Performance Characteristics





300446p0

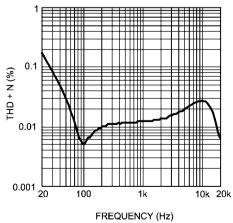
THD+N vs Frequency V_{DD} = 5V, R_L = 8Ω , P_{OUT} = 600mW Speaker Mode 1



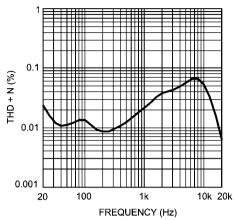
300446p2

300446q3

THD+N vs Frequency $V_{DD} = 3.6V, \, R_L = 8\Omega, \, P_{OUT} = 20mW$ Headphone Mode

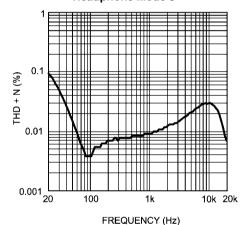


THD+N vs Frequency V_{DD} = 3.6V, R_L = 8 Ω , P_{OUT} = 300mW Speaker Mode 1



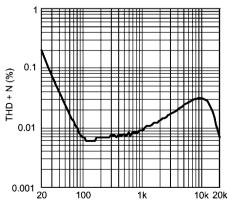
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THD+N vs Frequency $\label{eq:VDD} \begin{aligned} V_{DD} &= 3.3V, \ R_L = 32\Omega, \ P_{OUT} = 20mW \\ &\text{Headphone Mode 8} \end{aligned}$



300446q2

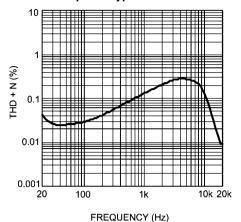
THD+N vs Frequency $V_{DD} = 5V, R_L = 32\Omega, P_{OUT} = 20mW$ Headphone Mode 8



FREQUENCY (Hz)

300446q4

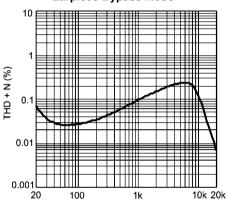
THD+N vs Frequency $\begin{aligned} & \text{V}_{\text{DD}} = 3.3\text{V}, \, \text{R}_{\text{L}} = 8\Omega, \, \text{P}_{\text{OUT}} = 20\text{mW} \\ & \text{Earpiece Bypass Mode} \end{aligned}$



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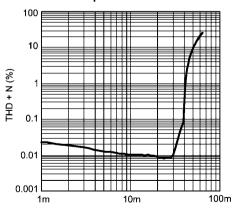
THD+N vs Frequency $$\begin{split} &V_{DD} = 5V, \ R_L = 8\Omega, \ P_{OUT} = 60mW \\ &Earpiece \ Bypass \ Mode \end{split}$$



FREQUENCY (Hz)

30044606

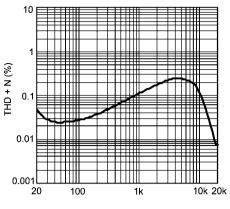
THD+N vs Output Power $V_{DD} = 3.3V, R_L = 32\Omega, f = 1 \text{kHz}$ Headphone Mode 8



OUTPUT POWER (W)

300446p4

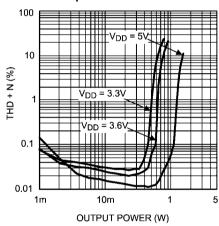
THD+N vs Frequency $\begin{aligned} & \text{V}_{\text{DD}} = 3.6\text{V}, \, \text{R}_{\text{L}} = 8\Omega, \, \text{P}_{\text{OUT}} = 30\text{mW} \\ & \text{Earpiece Bypass Mode} \end{aligned}$



FREQUENCY (Hz)

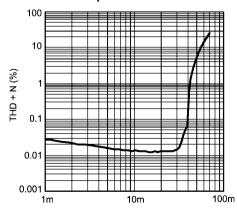
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THD+N vs Output Power $R_L = 8\Omega$, f = 1kHz Speaker Mode 1



300446p7

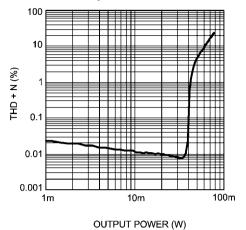
THD+N vs Output Power V_{DD} = 3.6V, R_L = 32 Ω , f = 1kHz Headphone Mode 8



OUTPUT POWER (W)

300446p5

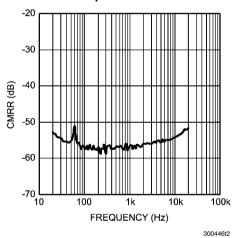
THD+N vs Output Power V_{DD} = 5V, R_L = 32Ω , f = 1kHz Headphone Mode 8



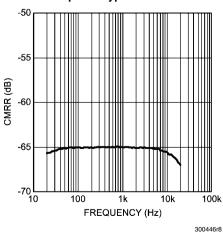
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300446p6

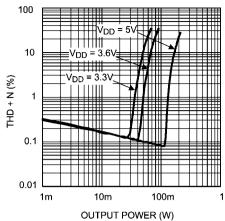
CMRR vs Frequency $V_{DD} = 3.3V, V_{CM} = 1V_{P,P} R_L = 8\Omega$ Loudspeaker Mode 1



CMRR vs Frequency $V_{DD} = 3.3V, V_{CM} = 1V_{P-P} R_L = 8\Omega$ Earpiece Bypass Mode

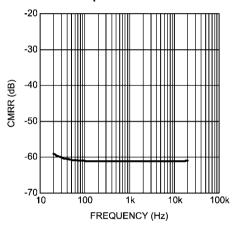


THD+N vs Output Power $R_L = 8\Omega$, f = 1kHz Earpiece Bypass Mode



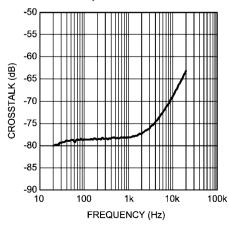
300446p3

 $\begin{array}{c} \text{CMRR vs Frequency} \\ \text{V}_{\text{DD}} = 3.3 \text{V}, \, \text{V}_{\text{CM}} = 1 \text{V}_{\text{P-P}} \, \text{R}_{\text{L}} = 32 \Omega \\ \text{Headphone Mode 4} \end{array}$

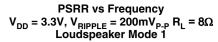


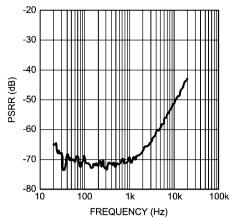
300446t3

 $\begin{array}{c} \text{Crosstalk vs Frequency} \\ \text{V}_{\text{DD}} = 3.3 \text{V}, \, \text{V}_{\text{CM}} = 1 \text{V}_{\text{P-P}} \, \text{R}_{\text{L}} = 32 \Omega \\ \text{Headphone Mode 8} \end{array}$

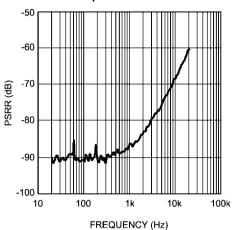


300446r9





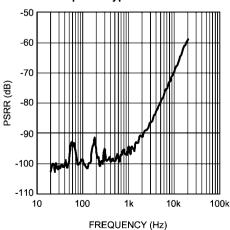
PSRR vs Frequency V_{DD} = 3.3V, V_{RIPPLE} = 200 $V_{P.P}$ R_L = 32 Ω Headphone Mode 4



300446r3

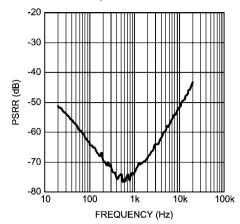
300446t0

 $\begin{aligned} & \text{PSRR vs Frequency} \\ \text{V}_{\text{DD}} = 3.3 \text{V}, \, \text{V}_{\text{RIPPLE}} = 200 \text{V}_{\text{P-P}} \, \text{R}_{\text{L}} = 8 \Omega \\ & \text{Earpiece Bypass Mode} \end{aligned}$



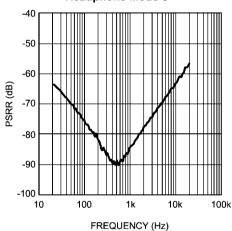
300446r5

PSRR vs Frequency $V_{DD}=3.3V,\,V_{RIPPLE}=200V_{P.P}\,R_L=8\Omega$ Loudspeaker Mode 2



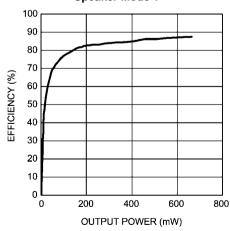
300446t1

PSRR vs Frequency V_{DD} = 3.3V, V_{RIPPLE} = 200 $V_{P.P}$ R_L = 32 Ω Headphone Mode 8



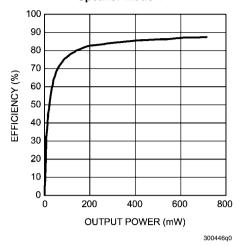
300446r4

Efficiency vs Output Power V_{DD} = 3.3V, R_L = 8 Ω , f = 1kHz Speaker Mode 1

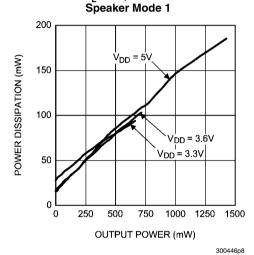


300446p9

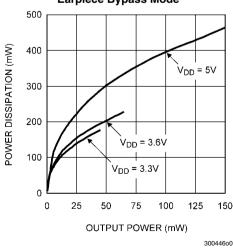
Efficiency vs Output Power $V_{DD} = 3.6V$, $R_L = 8\Omega$, f = 1kHz Speaker Mode 1



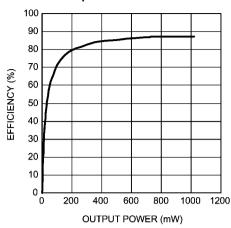
Power Dissipation vs Output Power $R_{L} = 8\Omega, \, f = 1 \text{kHz}$



Power Dissipation vs Output Power $R_L = 8\Omega, f = 1 \text{kHz}$ Earpiece Bypass Mode

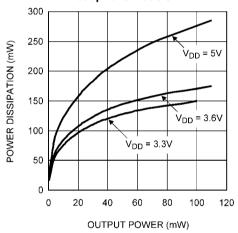


Efficiency vs Output Power V_{DD} = 5V, R_L = 8 Ω , f = 1kHz Speaker Mode 1



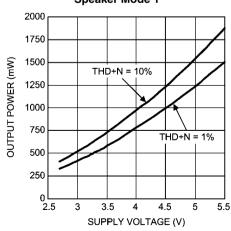
300446q1

Power Dissipation vs Output Power $R_L = 32\Omega, \, f = 1 \text{kHz}$ Headphone Mode 8



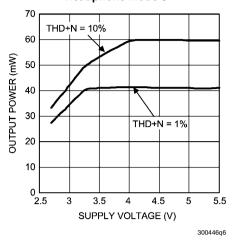
30044601

Output Power vs Supply Voltage $R_L = 8\Omega$, f = 1kHz Speaker Mode 1

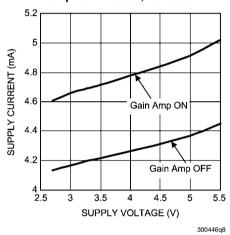


300446q7

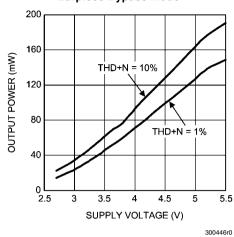
Output Power vs Supply Voltage $R_L = 32\Omega$, f = 1kHz Headphone Mode 8



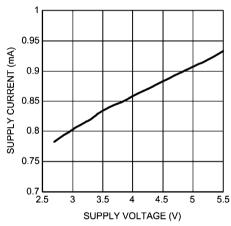
Supply Current vs Supply Voltage Headphone Mode 1, No Load



Output Power vs Supply Voltage $R_L = 8\Omega$, f = 1kHz Earpiece Bypass Mode



Supply Current vs Supply Voltage Earpiece Bypass Mode, No Load



300446q9

Application Information

I²C COMPATIBLE INTERFACE

The LM49150 is controlled through an I²C compatible serial interface that consists of a serial data line (SDA) and a serial clock (SCL). The clock line is uni-directional. The data line is bi-directional (open drain). The LM49150 and the master can communicate at clock rates up to 400kHz. Figure 2 shows the I²C interface timing diagram. Data on the SDA line must be stable during the HIGH period of SCL. The LM49150 is a transmit/receive slave-only device, reliant upon the master to generate the SCL signal. Each transmission sequence is framed by a START condition and a STOP condition (Figure 3). Each data word, device address and data, transmitted over the bus is 8 bits long and is always followed by an acknowledge pulse (Figure 4). The LM49150 device address is 11111000.

I²C INTERFACE POWER SUPPLY PIN (I²CV_{DD})

The LM49150's I²C interface is powered up through the I²CV_{DD} pin. The LM49150's I²C interface operates at a voltage level set by the I²CV_{DD} pin which can be set independent to that of the main power supply pin V_{DD} . This is ideal whenever logic levels for the I²C interface are dictated by a microcontroller or microprocessor that is operating at a lower supply voltage than the main battery of a portable system.

I2C BUS FORMAT

The I²C bus format is shown in Figure 4. The START signal, the transition of SDA from HIGH to LOW while SCL is HIGH, is generated, alerting all devices on the bus that a device address is being written to the bus.

The 7-bit device address is written to the bus, most significant bit (MSB) first, followed by the R/\overline{W} bit. $R/\overline{W}=0$ indicates the master is writing to the slave device, $R/\overline{W}=1$ indicates the master wants to read data from the slave device. Set $R/\overline{W}=0$; the LM49150 is a WRITE-ONLY device and will not respond to the $R/\overline{W}=1$. The data is latched in on the rising edge of the clock. Each address bit must be stable while SCL is HIGH. After the last address bit is transmitted, the master device releases SDA, during which time, an acknowledge clock pulse is generated by the slave device. If the LM49150 receives the correct address, the device pulls the SDA line low, generating an acknowledge bit (ACK).

Once the master device registers the ACK bit, the 8-bit register data word is sent. Each data bit should be stable while SCL is HIGH. After the 8-bit register data word is sent, the LM49150 sends another ACK bit. Following the acknowledgement of the register data word, the master issues a STOP bit, allowing SDA to go high while SCL is high.

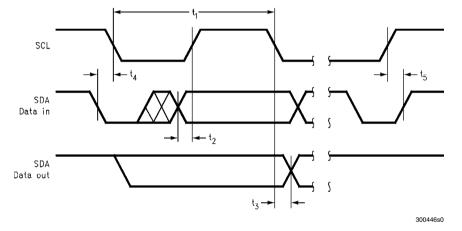


FIGURE 2. I²C Timing Diagram

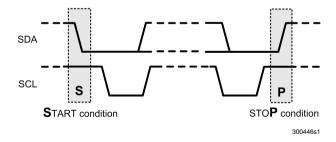


FIGURE 3. Start and Stop Diagram

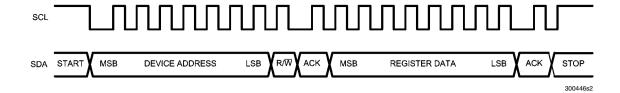


FIGURE 4. Start and Stop Diagram

TABLE 1. Chip Address

	B7	В6	B5	B4	В3	B2	B1	B0 (R/W)
Chip Address	1	1	1	1	1	0	0	0

TABLE 2. Control Registers

	B7	В6	B5	B4	В3	B2	B1	В0
Shutdown Control	0	0	Spread	GAMP_SD	0	I ² CV _{DD} _SD	Turn_On	PWR_On
			Spectrum				_Time	
Output Mode Control	0	1	EP	HPR_SD	мс3	MC2	MC1	MC0
			Bypass		(HP L&R)	(HP Mono)	(LS L&R)	(LS Mono)
Output Gain Control	1	0	0	INPUT_MUTE	LS_GAIN	HP_GAIN2	HP_GAIN1	HP_GAIN0
Mono Input Volume	1	0	1	MG4	MG3	MG2	MG1	MG0
Control								
Left Input Volume Control	1	1	0	LG4	LG3	LG2	LG1	LG0
Right Input Volume Control	1	1	1	RG4	RG3	RG2	RG1	RG0

TABLE 3. Shutdown Control Register

Bit	Name	Value	Description		
D.C.	Course of Consisterium	0	Spread Spectrum Disabled		
B5	Spread Spectrum	1	Spread Spectrum Enabled		
		0	Normal Operation		
B4	GAMP_SD	1	Disables the gain amplifiers that are not in use, to minimize I _{DD} . Recommended for Output Modes 1, 2, 4, 5, 8, 10		
B3		0			
B2	I ² CV _{DD} _SD	0	I ² CV _{DD} acts as an active low RESET input. If I ² CV _{DD} drops below 1.1V, the device resets and the I ² C registers are restored to their default state.		
		1	Normal Operation. I ² CV _{DD} voltage does not reset the device.		
D4	Turn On Time	0	Normal Turn-On Time (27ms)		
B1	Turn_On_Time	1	Fast Turn-On Time (15ms)		
В0	DWD On	0	Device Disabled		
ВО	PWR_On	1	Device Enabled		

TABLE 4. Output Mode Control Register

Bit	Name	Value	Description
		0	Normal Output Mode Operation
B5	EP Bypass	1	Speaker and Headphone amplifier goes into shutdown mode and enables Receiver Bypass path
B4	HPR_SD	0	Normal Operation
В4		HPH_SD 1	1

TABLE 5. Output Mode Selection (see legend below)

Output Mode Number	мсз	MC2	MC1	МСО	LS Output	HP R Output	HP L Output
0	0	0	0	0	SD	SD	SD
1	0	0	0	1	G _P x M	SD	SD
2	0	0	1	0	2 x (G _L x L + G _R x R)	SD	SD
3	0	0	1	1	2 x (G _L x L + G _R x R) + G _P x M	SD	SD
4	0	1	0	0	SD	G _P x M/2	G _P x M/2
5	0	1	0	1	G _P x M	G _P x M/2	G _P x M/2
6	0	1	1	0	$2 \times (G_L \times L + G_R \times R)$	G _P x M/2	G _P x M/2
7	0	1	1	1	2 x (G _L x L + G _R x R) + G _P x M	G _P x M/2	G _P x M/2
8	1	0	0	0	SD	G _R x R	G _L x L
9	1	0	0	1	G _P x M	G _R x R	G _L x L
10	1	0	1	0	2 x (G _L x L + G _R x R)	G _R x R	G _L x L
11	1	0	1	1	2 x (G _L x L + G _R x R) + G _P x M	G _R x R	G _L x L
12	1	1	0	0	SD	$G_R \times R + G_P \times M/2$	$G_L \times L + G_P \times M/2$
13	1	1	0	1	G _P x M	$G_R \times R + G_P \times M/2$	$G_L \times L + G_P \times M/2$
14	1	1	1	0	$2 \times (G_L \times L + G_R \times R)$	$G_R \times R + G_P \times M/2$	$G_L \times L + G_P \times M/2$
15	1	1	1	1	2 x (G _L x L + G _R x R) + G _P x M	$G_R \times R + G_P \times M/2$	$G_L \times L + G_P \times M/2$

MC3: HP Select L and R In MC2: HP Select Mono In MC1: Loud Speaker Select L and R In MC0: Loud Speaker Select Mono In

M : Phone In (Mono)
R: Right In

L: Left In SD: Shutdown

G_P: Phone In (Mono) Volume Control Gain G_R: Right Stereo Volume Control Gain G_L: Left Stereo Volume Control Gain

MC1	MC0	LSOUT
0	0	SD
0	1	M
1	0	L+R
1	1	M+L+R

MC3	MC2	HPR Output	HPL Output
0	0	SD	SD
0	1	М	M
1	0	L	R
1	1	M+L	M+R

TABLE 6. Output Gain Control (Loudspeaker)

Bit	Value	Gain (dB)
LC CAIN	0	+6
LS_GAIN	1	+12

TABLE 7. Headphone Output Gain Setting

HP_Gain2	HP_Gain1	HP_Gain0	Gain (dB)
0	0	0	0
0	0	1	-1.2
0	1	0	-2.5
0	1	1	-4.0
1	0	0	-6.0
1	0	1	-8.5
1	1	0	-12
1	1	1	-18

TABLE 8. Volume Control Table

Volume Step	(1) xG4	xG3	xG2	xG1	xG0	(2) Gain (dB)
1	0	0	0	0	0	-80.00
2	0	0	0	0	1	-46.50
3	0	0	0	1	0	-40.50
4	0	0	0	1	1	-34.50
5	0	0	1	0	0	-30.00
6	0	0	1	0	1	-27.00
7	0	0	1	1	0	-24.00
8	0	0	1	1	1	-21.00
9	0	1	0	0	0	-18.00
10	0	1	0	0	1	-15.00
11	0	1	0	1	0	-13.50
12	0	1	0	1	1	-12.00
13	0	1	1	0	0	-10.50
14	0	1	1	0	1	-9.00
15	0	1	1	1	0	-7.50
16	0	1	1	1	1	-6.00
17	1	0	0	0	0	-4.50
18	1	0	0	0	1	-3.00
19	1	0	0	1	0	-1.50
20	1	0	0	1	1	0.00
21	1	0	1	0	0	1.50
22	1	0	1	0	1	3.00
23	1	0	1	1	0	4.50
24	1	0	1	1	1	6.00
25	1	1	0	0	0	7.50
26	1	1	0	0	1	9.00
27	1	1	0	1	0	10.50
28	1	1	0	1	1	12.00
29	1	1	1	0	0	13.50
30	1	1	1	0	1	15.00
31	1	1	1	1	0	16.50
32	1	1	1	1	1	18.00

^(1.) x = M, L and R

SHUTDOWN FUNCTION

The LM49150 features the following shutdown controls.

Bit B4 (GAMP_SD) of the SHUTDOWN CONTROL register controls the gain amplifiers. When GAMP_SD = 1, it disables the gain amplifiers that are not in use. For example, in Modes 1, 4 and 5, the Mono inputs are in use, so the Left and Right input gain amplifiers are disabled, causing the $\rm I_{DD}$ to be minimized.

Bit B0 (PWR_On) of the SHUTDOWN CONTROL register is the global shutdown control for the entire device. Set PWR_On = 0 for normal operation. PWR_On = 1 overrides any other shutdown control bit.

OUTPUT MODE CONTROL

In the LM49150 OUTPUT MODE CONTROL register (Table 4), Bit B5 (EP Bypass) controls the operation of the Earpiece Bypass path. If EP Bypass = 0, it would act under normal output mode operation set by bits B3, B2, B1, and B0. If EP

Bypass = 1, it overrides the B3, B2, B1, and B0 Bits and enables the Receiver Bypass path, a class AB amplifier, to the speaker output.

Bit B4 (HPR_SD) of the OUPUT MODE CONTROL register controls the right headphone shutdown. If HPR_SD = 1, the right headphone output is disabled.

DIFFERENTIAL AMPLIFIER EXPLANATION

The LM49150 features a differential input stage, which offers improved noise rejection compared to a single-ended input amplifier. Because a differential input amplifier amplifies the difference between the two input signals, any component common to both signals is cancelled. An additional benefit of the differential input structure is the possible elimination of the DC input blocking capacitors. Since the DC component is common to both inputs, and thus cancelled by the amplifier, the LM49150 can be used without input coupling capacitors when configured with a differential input signal.

^(2.) Gain / Attenuation is from input to output

SINGLE-ENDED INPUT CONFIGURATION

The left and right stereo inputs of the LM49150 are configured for single-ended sources (see Figure 1).

INPUT CAPACITOR SELECTION

Input capacitors may be required for some applications, or when the audio source is single-ended. Input capacitors block the DC component of the audio signal, eliminating any conflict between the DC component of the audio source and the bias voltage of the LM49150. The input capacitors create a high-pass filter with the input resistors $R_{\rm IN}$. The -3dB point of the high-pass filter is found using Equation (1) below.

$$f = 1 / 2\pi R_{IN} C_{IN} \quad (Hz)$$
 (1)

Where the value of $R_{\rm IN}$ is given in the Electrical Characteristics Table.

High-pass filtering the audio signal helps protect the speakers. When the LM49150 is using a single-ended source, power supply noise on the ground is seen as an input signal. Setting the high-pass filter point above the power supply noise frequencies, 217Hz in a GSM phone, for example, filters out the noise such that it is not amplified and heard on the output. Capacitors with a tolerance of 10% or better are recommended for impedance matching and improved CMRR and PSRR.

INPUT MIXER/MULTIPLEXER

The LM49150 includes a comprehensive mixer multiplexer controlled through the I²C interface. The mixer/multiplexer allows any input combination to appear on any output of LM49150. Multiple input paths can be selected simultaneously. Under these conditions, the selected inputs are mixed together and output on the selected channel. Table 5 shows how the input signals are mixed together for each possible input selection.

CLASS D AMPLIFIER

The LM49150 features a high-efficiency, filterless, class D amplifier, which features a filterless modulation scheme. When there is no input signal applied, the output switches between $V_{\rm DD}$ and GND at a 50% duty cycle. Since the outputs of the LM49150 class D amplifier are differential and in phase, the result is zero net voltage across the speaker and no load current during the ideal state, thus conserving power. The switching frequency of each output is 300kHz.

When an input signal is applied, the duty cycle(pulse width) changes. For increasing output voltages, the duty cycle of one output increases while the duty cycle of the output decreases. For decreasing output voltages, the converse occurs. The difference between the two pulse widths yields the differential output voltage across the load.

SPREAD SPECTRUM

The LM49150 features a filterless spread spectrum modulation scheme. The switching frequency varies by +/-30% about a 300kHz center frequency, reducing the wideband spectral content, reducing EMI emissions radiated by the speaker and associated cables and traces. When a fixed frequency class D exhibits large amounts of spectral energy at multiples of switching frequency, the spread spectrum architecture of the LM49150 spreads that energy over a larger bandwidth. The cycle-to-cycle variation of the switching period does not affect the audio reproduction, efficiency, or PSRR. To enable

spread spectrum, set the spread spectrum bit, B5 = 1 of the SHUTDOWN CONTROL register (see Table 3).

ENHANCED EMMISIONS SUPPRESSION (E2S)

The LM49150 features National's patented E²S system that reduces EMI, while maintaining high quality audio reproduction and efficiency. The LM49150 features Edge Rate Control (ERC) that greatly reduces the high frequency components of the output square waves by controlling the output rise and fall times, slowing the transitions to reduce RF emissions, while optimizing THD+N and efficiency performance.

LDO GENERAL INFORMATION

The LM49150 has different supplies for each portion of the device, allowing for the optimum combination of headroom, power dissipation and noise immunity. The speaker amplifiers are powered from $\rm LSV_{DD}.$ The ground reference headphone amplifiers are powered from the internal LDO. The separate power supplies allow the loudspeaker amplifier to operate from a higher voltage for maximum headroom, while the headphone amplifiers operate from a lower voltage, improving power dissipation.

GROUND REFERENCED HEADPHONE AMPLIFIER

The LM49150 features a low noise inverting charge pump that generates an internal negative supply voltage. This allows the headphone outputs to be biased about GND instead of a nominal DC voltage, like traditional headphone amplifiers. Because there is no DC component, the large DC blocking capacitors (typically 220uF) are not necessary. The coupling capacitors are replaced by two small ceramic charge pump capacitors, saving board space and cost. Eliminating the output coupling capacitors also improves low frequency response. In traditional headphone amplifiers, the headphone impedance and the output capacitor from a high-pass filter that not only blocks the DC component of the output, but also attenuates low frequencies, impacting the bass response. Because the LM49150 does not require the output coupling capacitors, the low frequency response of the device is not degraded by external components. In addition to eliminating the output coupling capacitors, the ground referenced output nearly doubles the available dynamic range of the LM49250 headphone amplifiers when compared to a traditional headphone amplifier operating from the same supply voltage.

CHARGE PUMP CAPACITOR SELECTION

Use low ESR ceramic capacitors (less than $100m\Omega$) for optimum performance.

CHARGE PUMP FLYING CAPACITOR (C1)

The flying capacitor (C1), see Figure 1, affects the load regulation and output impedance of the charge pump. A C1 value that is too low results in a loss of current drive, leading to a loss of amplifier headroom. A higher valued C1 improves load regulation and lowers charge pump output impedance to an extent. Above 2.2 μ F, the R_{DS(ON)} of the charge pump switches and the ESR of C1 and Cs5 dominate the output impedance. A lower value capacitor can be used in systems with low maximum output power requirements.

CHARGE PUMP HOLD CAPACITOR (Cs5)

The value and ESR of the hold capacitor (Cs5) directly affects the ripple on CPV_SS . Increasing the value of Cs5 reduces output ripple. Decreasing the ESR of Cs5 reduces both output ripple and charge pump output impedance. A lower value capacitor can be used in systems with low maximum output power requirements.

LM49150 Demoboard Bill Of Materials

TABLE 9. Bill Of Materials

Location	Qty	Description	Part Number	Manufacturer
CIN2, CIN1	2	0.22uF, 1206, 10V, X7R Ceramic Capacitor	GRM319R71C224KA01D	Murata
CS4, CS2	2	0.1uF, 0805, 10V, X7R Ceramic Capacitor	GRM219R71C104KA01D	Murata
CS7	1	1.0uF, 0805, 10V, X7R Ceramic Capacitor	GRM21BR71A105KA01L	Murata
CIN3, CIN4	2	1.0uF 1206, 10V, X7R Ceramic Capacitor	GRM319R71C105KAA3D	Murata
CS5, C1	2	2.2uF, 0603, 10V, X7R, Ceramic Capacitor	GRM188R71A225KE15D	Murata
CS1, CS3, CS6	3	2.2uF, Size A, Tantalum Capactior	293D225X9010A2TE3	Vishay
U2	1	LM49150, 16 bump uSMD	LM49510	NSC
R1, R2	2	5K ohm 1/10W 0.05% 0603 SMD	CRCW06035R1KJNEA	Vishay
J11, J12, J13, J14	4	3-Header		
J1, J2, J3, J7, J8, J9, J10	7	2-Header		
J6	1	Header_3M 8516-4500PL		
U1	1	Headphone Jack		

Layout Guidelines

Minimize trace impedance of the power, ground and all output traces for optimum performance. Voltage loss due to trace resistance between the LM49150 and the load results in decreased output power and efficiency. Trace resistance between the power supply and the GND of the LM49150 has the same effect as a poorly regulated supply, increased ripple and reduced peak output power. Use wide traces, for power-supply inputs and amplifier outputs to minimize losses due to trace resistance, as well as providing heat dissipation from the device. Proper grounding improves audio performance, minimizes crosstalk between channels and prevents switching noise from interfering with audio signal. Use of power and ground planes is recommended.

The following recommendations should be considered when laying out the different grounds of the LM49150. Refer to the Demo Board Schematic for the corresponding component designators. Bypass capacitors for ${\rm AV_{DD}}$ (CS7), ${\rm LSV_{DD}}$ (CS1, CS2), ${\rm V_{O(LDO)}}$ (CS3, CS4) should be grounded to the GND pin via a ground plane. Bypass capacitor for ${\rm CPV_{SS}}({\rm CS5})$ should be grounded via a wide trace or a ground plane to the CPGND pin. The headphone grounds should be connected to the GND via a separate trace also. This will help prevent noise from the charge pump from feeding into the power supplies and the output.

Place all digital components and digital signal traces as far as possible from analog components and traces. Do not run digital and analog traces in parallel on the same PCB layer.

Demo Board Schematic

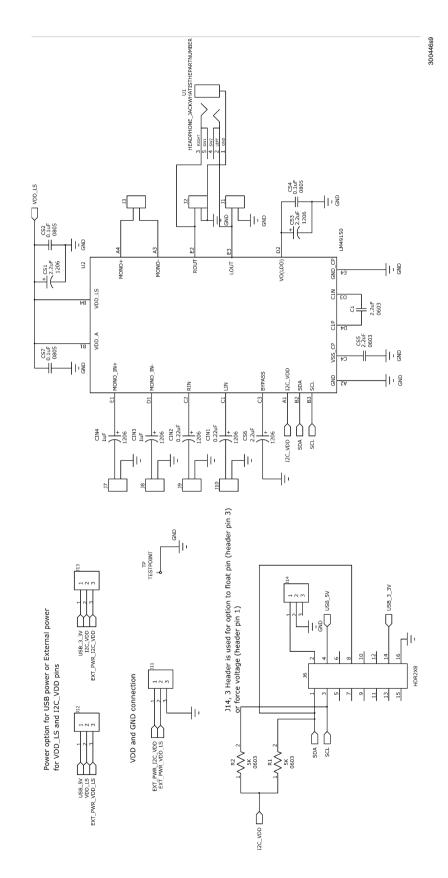
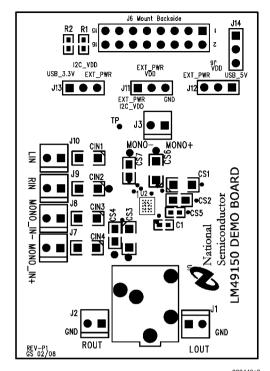
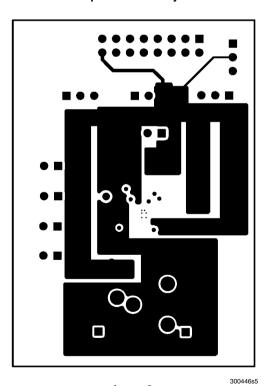


FIGURE 5. LM49150 Demo Board Schematic

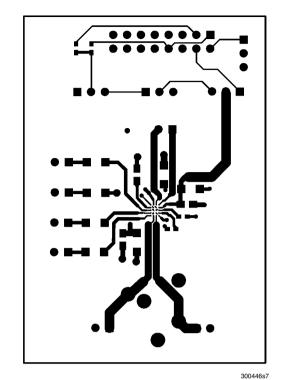
PC Board Layout



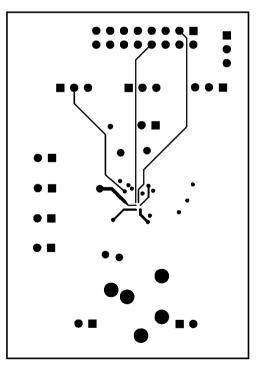
Top Silkscreen Layer



Layer 2

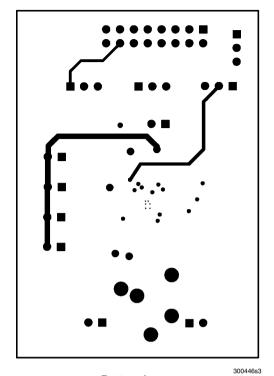


Top Layer

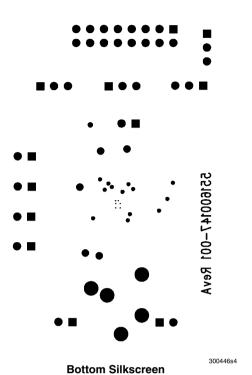


Layer 3

300446s6



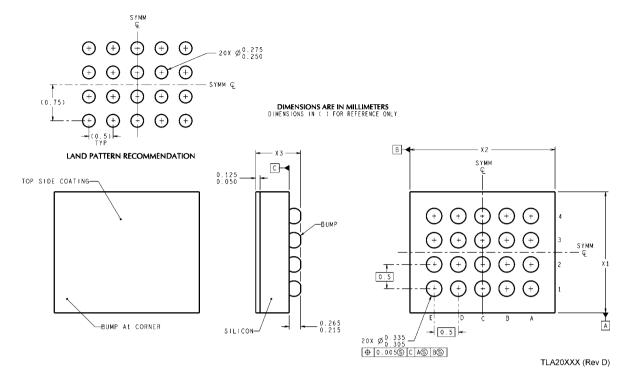




Revision History

Rev	Date	Description	
1.0	08/27/08	Initial release.	
1.01	09/09/08	Edited Table 6.	
1.02	03/04/09	Added the Layout Guidelines section.	

Physical Dimensions inches (millimeters) unless otherwise noted



20 – Bump micro SMD Package Order Number LM49150TL NS Package Number TLA20KGA X_1 = 2225 μ m, X_2 = 2644 μ m, X_3 = 600 μ m

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